

MITSUBISHI LASER DIODES

ML7xx32 SERIES

Notice: Some parametric limits are subject to change

10Gbps InGaAsP DFB LASER DIODE

**TYPE
NAME**

ML792E32/ML792H32

DESCRIPTION

ML7xx32 series are uncooled DFB (Distributed Feedback) laser diodes for 10Gbps transmission emitting light beam at 1310nm. $\lambda/4$ phase shifted grating structure is employed to obtain excellent SMSR performance under 10Gbps modulation. Furthermore, ML7xx32 is able to operate in the wide temperature range from 0°C to 85°C without temperature control.

APPLICATION

10Gbps Ethernet/Short Reach

***Specification Note

Type	Matching Resistance :Rs
ML792E32-01 ML792H32-01	42 $\pm$ 1 ohm

FEATURES

- $\lambda/4$ phase shifted grating structure
- Wide temperature range operation (0°C to 85°C)
- High side-mode-suppression-ratio (typical 45dB)
- High resonance frequency (typical 15GHz)
- Chip-on-carrier

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
If	Laser forward current	-	120	mA
VRL	Laser reverse voltage	-	2	V
Tc	Operation temperature	-	0 ~ +85	°C
Tstg	Storage temperature	-	-40 ~+100	°C

ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25°C)

Symbol	Parameter	Conditions	Limits			Unit
			Min.	Typ	Max	
Ith	Threshold current	CW	-	9	20	mA
		CW, Tc=85°C	-	30	40	mA
Iop	Operation current	CW, Po=5mW	-	30	40	mA
		CW, Po=5mW, Tc=85°C	-	70	90	mA
Vop	Operating voltage	CW, Po=5mW	-	1.1	1.8	V
η	Slope efficiency	CW, Po=5mW	0.20	0.25	-	mW/mA
λ_p	Peak wavelength	CW, Po=5mW, Tc= 0°C ~ +85°C	1290	1310	1330	nm
SMSR	Side mode suppression ratio	CW, Po=5mW, Tc= 0°C ~ +85°C	35	45	-	dB
$\theta_{\parallel}$	Beam divergence angle (parallel)	CW, Po=5mW	-	25	40	deg.
$\theta_{\perp}$	(perpendicular)	CW, Po=5mW	-	30	45	deg.
f _r	Resonance frequency	10Gbps, Ex=7dB, Vpp=2.0V	-	15	-	GHz
tr	Rise time(20%-80%)	10Gbps, Ex=7dB, Vpp=2.0V	-	30	40	psec
tf	Fall time(20%-80%)	4th order Bessel - Thompson Filter	-	30	40	



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ELECTRIC

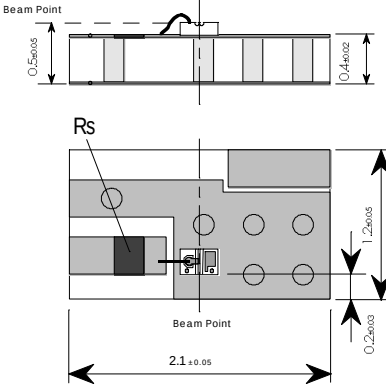
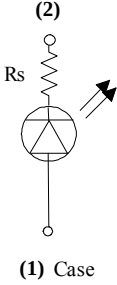
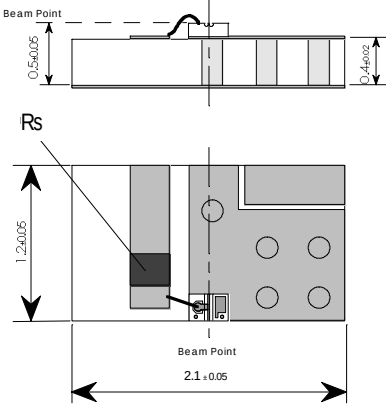
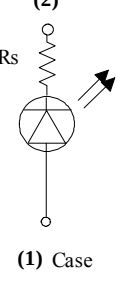
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10Gbps InGaAsP DFB-LASER DIODE

OUTLINE DRAWINGS

ML792E32		 (2) Rs (1) Case
ML792H32		 (2) Rs (1) Case

